# 74AUP2G132

## Low-power dual 2-input NAND Schmitt trigger

Rev. 11 — 26 July 2023

**Product data sheet** 

### 1. General description

The 74AUP2G132 is a dual 2-input NAND gate with Schmitt-trigger inputs. This device ensures very low static and dynamic power consumption across the entire  $V_{CC}$  range from 0.8 V to 3.6 V. This device is fully specified for partial power down applications using  $I_{OFF}$ . The  $I_{OFF}$  circuitry disables the output, preventing the potentially damaging backflow current through the device when it is powered down.

### 2. Features and benefits

- Wide supply voltage range from 0.8 V to 3.6 V
- CMOS low power dissipation
- High noise immunity
- Low static power consumption; I<sub>CC</sub> = 0.9 μA (maximum)
- Latch-up performance exceeds 100 mA per JESD 78 Class II Level B
- Overvoltage tolerant inputs to 3.6 V
- Low noise overshoot and undershoot < 10 % of V<sub>CC</sub>
- I<sub>OFF</sub> circuitry provides partial Power-down mode operation
- Complies with JEDEC standards:
  - JESD8-12 (0.8 V to 1.3 V)
  - JESD8-11 (0.9 V to 1.65 V)
  - JESD8-7 (1.65 V to 1.95 V)
  - JESD8-5 (2.3 V to 2.7 V)
  - JESD8C (2.7 V to 3.6 V)
- ESD protection:
  - HBM: ANSI/ESDA/JEDEC JS-001 class 3A exceeds 5000 V
  - CDM: ANSI/ESDA/JEDEC JS-002 class C3 exceeds 1000 V
- Multiple package options
- Specified from -40 °C to +85 °C and -40 °C to +125 °C

## 3. Applications

- · Wave and pulse shaper
- Astable multivibrator
- Monostable multivibrator



### Low-power dual 2-input NAND Schmitt trigger

# 4. Ordering information

**Table 1. Ordering information** 

Type number	Package							
	Temperature range	mperature range Name Description						
74AUP2G132DC	-40 °C to +125 °C	VSSOP8	plastic very thin shrink small outline package; 8 leads; body width 2.3 mm	SOT765-1				
74AUP2G132GT	-40 °C to +125 °C	XSON8	plastic extremely thin small outline package; no leads; 8 terminals; body 1 × 1.95 × 0.5 mm	SOT833-1				
74AUP2G132GF	-40 °C to +125 °C	XSON8	extremely thin small outline package; no leads; 8 terminals; body 1.35 × 1 × 0.5 mm	SOT1089				
74AUP2G132GN	-40 °C to +125 °C	XSON8	extremely thin small outline package; no leads; 8 terminals; body 1.2 × 1.0 × 0.35 mm	<u>SOT1116</u>				
74AUP2G132GS	-40 °C to +125 °C	XSON8	extremely thin small outline package; no leads; 8 terminals; body 1.35 × 1.0 × 0.35 mm	<u>SOT1203</u>				
74AUP2G132GX	-40 °C to +125 °C	X2SON8	plastic thermal enhanced extremely thin small outline package; no leads; 8 terminals; body 1.35 × 0.8 × 0.32 mm	SOT1233-2				

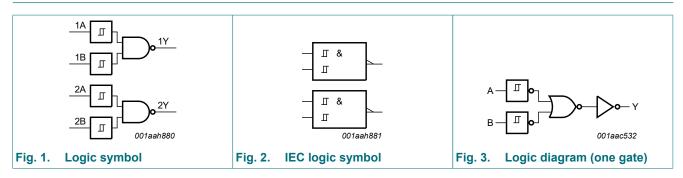
## 5. Marking

Table 2. Marking codes

Type number	Marking code[1]
74AUP2G132DC	aE2
74AUP2G132GT	aE2
74AUP2G132GF	аЕ
74AUP2G132GN	аЕ
74AUP2G132GS	аЕ
74AUP2G132GX	аЕ

<sup>[1]</sup> The pin 1 indicator is located on the lower left corner of the device, below the marking code.

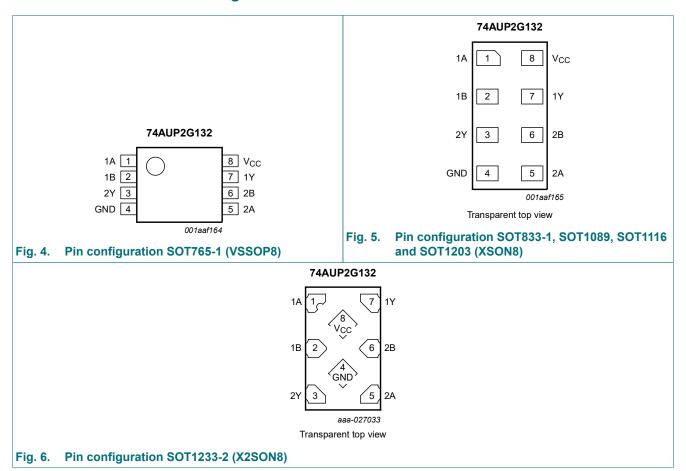
# 6. Functional diagram



Low-power dual 2-input NAND Schmitt trigger

# 7. Pinning information

### 7.1. Pinning



### 7.2. Pin description

#### Table 3. Pin description

Symbol	Pin	Description
1A, 2A	1, 5	data input
1B, 2B	2, 6	data input
GND	4	ground (0 V)
1Y, 2Y	7, 3	data output
Vcc	8	supply voltage

#### Low-power dual 2-input NAND Schmitt trigger

### 8. Functional description

#### **Table 4. Function table**

 $H = HIGH \ voltage \ level; \ L = LOW \ voltage \ level.$ 

Input	Output	
nA	nB	nY
L	L	Н
L	Н	Н
Н	L	Н
Н	Н	L

### 9. Limiting values

#### **Table 5. Limiting values**

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions		Min	Max	Unit
V <sub>CC</sub>	supply voltage			-0.5	+4.6	V
I <sub>IK</sub>	input clamping current	V <sub>I</sub> < 0 V		-50	-	mA
VI	input voltage		[1]	-0.5	+4.6	V
lok	output clamping current	V <sub>O</sub> < 0 V		-50	-	mA
Vo	output voltage	Active mode and Power-down mode	[1]	-0.5	+4.6	V
Io	output current	V <sub>O</sub> = 0 V to V <sub>CC</sub>		-	±20	mA
I <sub>CC</sub>	supply current			-	+50	mA
I <sub>GND</sub>	ground current			-50	-	mA
T <sub>stg</sub>	storage temperature			-65	+150	°C
P <sub>tot</sub>	total power dissipation	T <sub>amb</sub> = -40 °C to +125 °C				
		SOT765-1 (VSSOP8) SOT833-1 (XSON8) SOT1089 (XSON8) SOT1116 (XSON8) SOT1203 (XSON8)	[2] [3] [4] [5] [6]	- - - -	250 250 250 250 250	mW mW mW mW
		SOT1233-2 (X2SON8)	[7]	-	300	mW

- [1] The minimum input and output voltage ratings may be exceeded if the input and output current ratings are observed.
- [2] For SOT765-1 (VSSOP8) package: P<sub>tot</sub> derates linearly with 4.9 mW/K above 99 °C.
- [3] For SOT833-1 (XSON8) package: P<sub>tot</sub> derates linearly with 3.1 mW/K above 68 °C.
- [4] For SOT1089 (XSON8) package: P<sub>tot</sub> derates linearly with 4.0 mW/K above 88 °C.
- 5] For SOT1116 (XSON8) package: P<sub>tot</sub> derates linearly with 4.2 mW/K above 90 °C.
- For SOT1203 (XSON8) package: P<sub>tot</sub> derates linearly with 3.6 mW/K above 81 °C.
   For SOT1233-2 (X2SON8) package: P<sub>tot</sub> derates linearly with 7.7 mW/K above 118 °C.

### Low-power dual 2-input NAND Schmitt trigger

# 10. Recommended operating conditions

Table 6. Recommended operating conditions

Symbol	Parameter	Conditions	Min	Max	Unit
V <sub>CC</sub>	supply voltage		0.8	3.6	V
VI	input voltage		0	3.6	V
Vo	output voltage	Active mode	0	V <sub>CC</sub>	V
		Power-down mode; V <sub>CC</sub> = 0 V	0	3.6	V
T <sub>amb</sub>	ambient temperature		-40	+125	°C

### 11. Static characteristics

#### **Table 7. Static characteristics**

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
T <sub>amb</sub> = 2	5 °C	'				
V <sub>OH</sub>	HIGH-level output voltage	$V_I = V_{T+}$ or $V_{T-}$				
		I <sub>O</sub> = -20 μA; V <sub>CC</sub> = 0.8 V to 3.6 V	V <sub>CC</sub> - 0.1	-	-	V
		I <sub>O</sub> = -1.1 mA; V <sub>CC</sub> = 1.1 V	0.75 × V <sub>CC</sub>	-	-	V
		I <sub>O</sub> = -1.7 mA; V <sub>CC</sub> = 1.4 V	1.11	-	-	V
		I <sub>O</sub> = -1.9 mA; V <sub>CC</sub> = 1.65 V	1.32	-	-	V
		$I_{O}$ = -2.3 mA; $V_{CC}$ = 2.3 V	2.05	-	-	V
		I <sub>O</sub> = -3.1 mA; V <sub>CC</sub> = 2.3 V	1.9	-	-	V
		$I_{O}$ = -2.7 mA; $V_{CC}$ = 3.0 V	2.72	-	-	V
		$I_{O}$ = -4.0 mA; $V_{CC}$ = 3.0 V	2.6	-	-	V
$V_{OL}$	LOW-level output voltage	$V_I = V_{T+}$ or $V_{T-}$				
		$I_{O}$ = 20 $\mu$ A; $V_{CC}$ = 0.8 V to 3.6 V	-	-	0.1	V
		I <sub>O</sub> = 1.1 mA; V <sub>CC</sub> = 1.1 V	-	-	0.3 × V <sub>CC</sub>	V
		I <sub>O</sub> = 1.7 mA; V <sub>CC</sub> = 1.4 V	-	-	0.31	V
		I <sub>O</sub> = 1.9 mA; V <sub>CC</sub> = 1.65 V	-	-	0.31	V
		I <sub>O</sub> = 2.3 mA; V <sub>CC</sub> = 2.3 V	-	-	0.31	V
		I <sub>O</sub> = 3.1 mA; V <sub>CC</sub> = 2.3 V	-	-	0.44	V
		I <sub>O</sub> = 2.7 mA; V <sub>CC</sub> = 3.0 V	-	-	0.31	V
		I <sub>O</sub> = 4.0 mA; V <sub>CC</sub> = 3.0 V	-	-	0.44	V
I <sub>I</sub>	input leakage current	V <sub>I</sub> = GND to 3.6 V; V <sub>CC</sub> = 0 V to 3.6 V	-	-	±0.1	μΑ
I <sub>OFF</sub>	power-off leakage current	$V_{I}$ or $V_{O} = 0 \text{ V}$ to 3.6 V; $V_{CC} = 0 \text{ V}$	-	-	±0.2	μΑ
Δl <sub>OFF</sub>	additional power-off leakage current	V <sub>I</sub> or V <sub>O</sub> = 0 V to 3.6 V; V <sub>CC</sub> = 0 V to 0.2 V	-	-	±0.2	μΑ
I <sub>CC</sub>	supply current	V <sub>I</sub> = GND or V <sub>CC</sub> ; I <sub>O</sub> = 0 A; V <sub>CC</sub> = 0.8 V to 3.6 V	-	-	0.5	μA
ΔI <sub>CC</sub>	additional supply current	$V_1 = V_{CC} - 0.6 \text{ V}; I_O = 0 \text{ A};$ [1] $V_{CC} = 3.3 \text{ V}$	-	-	40	μA
Cı	input capacitance	$V_I$ = GND or $V_{CC}$ ; $V_{CC}$ = 0 V to 3.6 V	-	1.1	-	pF
Co	output capacitance	$V_O = GND; V_{CC} = 0 V$	-	1.7	-	pF

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Symbol	Parameter	Conditions	Min	Тур	Max	Unit
T <sub>amb</sub> = -4	10 °C to +85 °C					
V <sub>OH</sub>	HIGH-level output voltage	$V_I = V_{T+}$ or $V_{T-}$				T
		I <sub>O</sub> = -20 μA; V <sub>CC</sub> = 0.8 V to 3.6 V	V <sub>CC</sub> - 0.1	-	-	V
		I <sub>O</sub> = -1.1 mA; V <sub>CC</sub> = 1.1 V	0.7 × V <sub>CC</sub>	-	-	V
		I <sub>O</sub> = -1.7 mA; V <sub>CC</sub> = 1.4 V	1.03	-	-	V
		I <sub>O</sub> = -1.9 mA; V <sub>CC</sub> = 1.65 V	1.30	-	-	V
		I <sub>O</sub> = -2.3 mA; V <sub>CC</sub> = 2.3 V	1.97	-	-	V
		I <sub>O</sub> = -3.1 mA; V <sub>CC</sub> = 2.3 V	1.85	-	-	V
		I <sub>O</sub> = -2.7 mA; V <sub>CC</sub> = 3.0 V	2.67	-	-	V
		I <sub>O</sub> = -4.0 mA; V <sub>CC</sub> = 3.0 V	2.55	-	-	V
V <sub>OL</sub>	LOW-level output voltage	$V_I = V_{T+}$ or $V_{T-}$				
		$I_O = 20 \mu A; V_{CC} = 0.8 \text{ V to } 3.6 \text{ V}$	-	-	0.1	V
		I <sub>O</sub> = 1.1 mA; V <sub>CC</sub> = 1.1 V	-	-	0.3 × V <sub>CC</sub>	V
		I <sub>O</sub> = 1.7 mA; V <sub>CC</sub> = 1.4 V	-	-	0.37	V
		I <sub>O</sub> = 1.9 mA; V <sub>CC</sub> = 1.65 V	-	-	0.35	V
		I <sub>O</sub> = 2.3 mA; V <sub>CC</sub> = 2.3 V	-	-	0.33	V
		I <sub>O</sub> = 3.1 mA; V <sub>CC</sub> = 2.3 V	-	-	0.45	V
		I <sub>O</sub> = 2.7 mA; V <sub>CC</sub> = 3.0 V	-	-	0.33	V
		I <sub>O</sub> = 4.0 mA; V <sub>CC</sub> = 3.0 V	-	-	0.45	V
I <sub>I</sub>	input leakage current	V <sub>I</sub> = GND to 3.6 V; V <sub>CC</sub> = 0 V to 3.6 V	-	-	±0.5	μA
I <sub>OFF</sub>	power-off leakage current	$V_{I}$ or $V_{O} = 0$ V to 3.6 V; $V_{CC} = 0$ V	-	-	±0.5	μA
Δl <sub>OFF</sub>	additional power-off leakage current	V <sub>I</sub> or V <sub>O</sub> = 0 V to 3.6 V; V <sub>CC</sub> = 0 V to 0.2 V	-	-	±0.6	μA
I <sub>CC</sub>	supply current	$V_{I}$ = GND or $V_{CC}$ ; $I_{O}$ = 0 A; $V_{CC}$ = 0.8 V to 3.6 V	-	-	0.9	μΑ
Δl <sub>CC</sub>	additional supply current	$V_1 = V_{CC} - 0.6 \text{ V}; I_O = 0 \text{ A};$ [1] $V_{CC} = 3.3 \text{ V}$	-	-	50	μA

### Low-power dual 2-input NAND Schmitt trigger

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
T <sub>amb</sub> = -4	0 °C to +125 °C				1	
V <sub>OH</sub>	HIGH-level output voltage	$V_I = V_{T+}$ or $V_{T-}$				
		I <sub>O</sub> = -20 μA; V <sub>CC</sub> = 0.8 V to 3.6 V	V <sub>CC</sub> - 0.11	-	-	V
		I <sub>O</sub> = -1.1 mA; V <sub>CC</sub> = 1.1 V	0.6 × V <sub>CC</sub>	-	-	V
		I <sub>O</sub> = -1.7 mA; V <sub>CC</sub> = 1.4 V	0.93	-	-	V
		I <sub>O</sub> = -1.9 mA; V <sub>CC</sub> = 1.65 V	1.17	-	-	V
		I <sub>O</sub> = -2.3 mA; V <sub>CC</sub> = 2.3 V	1.77	-	-	V
		I <sub>O</sub> = -3.1 mA; V <sub>CC</sub> = 2.3 V	1.67	-	-	V
		I <sub>O</sub> = -2.7 mA; V <sub>CC</sub> = 3.0 V	2.40	-	-	V
		I <sub>O</sub> = -4.0 mA; V <sub>CC</sub> = 3.0 V	2.30	-	-	V
V <sub>OL</sub>	LOW-level output voltage	$V_I = V_{T+}$ or $V_{T-}$				
		$I_O = 20 \mu A; V_{CC} = 0.8 \text{ V to } 3.6 \text{ V}$	-	-	0.11	V
		I <sub>O</sub> = 1.1 mA; V <sub>CC</sub> = 1.1 V	-	-	0.33 × V <sub>CC</sub>	V
		I <sub>O</sub> = 1.7 mA; V <sub>CC</sub> = 1.4 V	-	-	0.41	V
		I <sub>O</sub> = 1.9 mA; V <sub>CC</sub> = 1.65 V	-	-	0.39	V
		I <sub>O</sub> = 2.3 mA; V <sub>CC</sub> = 2.3 V	-	-	0.36	V
		I <sub>O</sub> = 3.1 mA; V <sub>CC</sub> = 2.3 V	-	-	0.50	V
		I <sub>O</sub> = 2.7 mA; V <sub>CC</sub> = 3.0 V	-	-	0.36	V
		I <sub>O</sub> = 4.0 mA; V <sub>CC</sub> = 3.0 V	-	-	0.50	V
l <sub>l</sub>	input leakage current	V <sub>I</sub> = GND to 3.6 V; V <sub>CC</sub> = 0 V to 3.6 V	-	-	±0.75	μΑ
I <sub>OFF</sub>	power-off leakage current	$V_{I}$ or $V_{O} = 0$ V to 3.6 V; $V_{CC} = 0$ V	-	-	±0.75	μΑ
Δl <sub>OFF</sub>	additional power-off leakage current	V <sub>I</sub> or V <sub>O</sub> = 0 V to 3.6 V; V <sub>CC</sub> = 0 V to 0.2 V	-	-	±0.75	μA
I <sub>CC</sub>	supply current	$V_{I}$ = GND or $V_{CC}$ ; $I_{O}$ = 0 A; $V_{CC}$ = 0.8 V to 3.6 V	-	-	1.4	μA
ΔI <sub>CC</sub>	additional supply current	$V_1 = V_{CC} - 0.6 \text{ V}; I_O = 0 \text{ A};$ [1] $V_{CC} = 3.3 \text{ V}$	-	-	75	μA

<sup>[1]</sup> One input at  $V_{CC}$  - 0.6 V, other input at  $V_{CC}$  or GND.

# 12. Dynamic characteristics

### **Table 8. Dynamic characteristics**

Voltages are referenced to GND (ground = 0 V); for test circuit see Fig. 8.

Symbol	Parameter	Conditions	T,	<sub>amb</sub> = 25 °	C		<sub>nb</sub> = o +85 °C	T <sub>an</sub> -40 °C to	<sub>nb</sub> = +125 °C	Unit
			Min	Typ[1]	Max	Min	Max	Min	Max	
$C_L = 5 p$	F									
t <sub>pd</sub>	propagation	nA or nB to nY; see Fig. 7 [2]								
	delay	V <sub>CC</sub> = 0.8 V	-	22.5	-	-	-	-	-	ns
		V <sub>CC</sub> = 1.1 V to 1.3 V	2.6	6.3	13.4	2.4	15.1	2.4	16.6	ns
		V <sub>CC</sub> = 1.4 V to 1.6 V	2.2	4.6	8.2	1.9	9.7	1.9	10.7	ns
		V <sub>CC</sub> = 1.65 V to 1.95 V	1.9	3.9	6.6	1.7	7.9	1.7	8.7	ns
		V <sub>CC</sub> = 2.3 V to 2.7 V	1.7	3.2	5.3	1.5	6.2	1.5	6.8	ns
		V <sub>CC</sub> = 3.0 V to 3.6 V	1.6	2.9	4.7	1.4	5.6	1.4	6.2	ns

### Low-power dual 2-input NAND Schmitt trigger

Symbol	Parameter	Conditions	T,	<sub>amb</sub> = 25 °	C.	T <sub>am</sub> -40 °C to	<sub>nb</sub> = o +85 °C	T <sub>an</sub> -40 °C to	<sub>nb</sub> = o +125 °C	Unit
			Min	Typ[1]	Max	Min	Max	Min	Max	
C <sub>L</sub> = 10	pF									
t <sub>pd</sub>	propagation	nA or nB to nY; see Fig. 7 [2]								
	delay	V <sub>CC</sub> = 0.8 V	-	26.1	-	-	-	-	-	ns
		V <sub>CC</sub> = 1.1 V to 1.3 V	3.0	7.2	15.4	2.7	17.3	2.7	19.0	ns
		V <sub>CC</sub> = 1.4 V to 1.6 V	2.5	5.2	9.3	2.2	11.0	2.2	12.1	ns
		V <sub>CC</sub> = 1.65 V to 1.95 V	2.3	4.5	7.5	2.0	9.0	2.0	9.9	ns
		V <sub>CC</sub> = 2.3 V to 2.7 V	2.1	3.8	6.1	1.8	7.2	1.8	7.9	ns
		V <sub>CC</sub> = 3.0 V to 3.6 V	2.0	3.5	5.5	1.8	6.5	1.8	7.2	ns
C <sub>L</sub> = 15	pF									
t <sub>pd</sub>	propagation	nA or nB to nY; see Fig. 7 [2]								
	delay	V <sub>CC</sub> = 0.8 V	-	29.6	-	-	-	-	-	ns
		V <sub>CC</sub> = 1.1 V to 1.3 V	3.3	8.0	17.2	3.0	19.4	3.0	21.3	ns
		V <sub>CC</sub> = 1.4 V to 1.6 V	2.8	5.8	10.4	2.5	12.3	2.5	13.5	ns
		V <sub>CC</sub> = 1.65 V to 1.95 V	2.6	5.0	8.3	2.3	10.0	2.3	11.0	ns
		V <sub>CC</sub> = 2.3 V to 2.7 V	2.3	4.2	6.7	2.1	7.9	2.1	8.7	ns
		V <sub>CC</sub> = 3.0 V to 3.6 V	2.2	3.9	6.1	2.0	7.3	2.0	8.0	ns
C <sub>L</sub> = 30	pF									
t <sub>pd</sub>	propagation	nA or nB to nY; see Fig. 7 [2]								
	delay	V <sub>CC</sub> = 0.8 V	-	39.9	-	-	-	-	-	ns
		V <sub>CC</sub> = 1.1 V to 1.3 V	4.3	10.2	22.6	3.8	25.4	3.8	27.9	ns
		V <sub>CC</sub> = 1.4 V to 1.6 V	3.6	7.3	13.3	3.2	15.8	3.2	17.4	ns
		V <sub>CC</sub> = 1.65 V to 1.95 V	3.2	6.3	10.6	2.9	12.8	2.9	14.1	ns
		V <sub>CC</sub> = 2.3 V to 2.7 V	3.0	5.3	8.5	2.7	10.1	2.7	11.1	ns
		V <sub>CC</sub> = 3.0 V to 3.6 V	2.8	5.0	7.8	2.7	9.2	2.7	10.1	ns
C <sub>L</sub> = 5 p	F, 10 pF, 15 p	F and 30 pF								
C <sub>PD</sub>	power dissipation	$f_i$ = 1 MHz; [3] V <sub>I</sub> = GND to V <sub>CC</sub>								
	capacitance	V <sub>CC</sub> = 0.8 V	-	2.6	-	-	-	-	-	pF
		V <sub>CC</sub> = 1.1 V to 1.3 V	-	2.9	-	-	-	-	-	pF
		V <sub>CC</sub> = 1.4 V to 1.6 V	-	3.0	-	-	-	-	-	pF
		V <sub>CC</sub> = 1.65 V to 1.95 V	-	3.2	-	-	-	-	-	pF
		V <sub>CC</sub> = 2.3 V to 2.7 V	-	3.8	-	-	-	-	-	pF
		V <sub>CC</sub> = 3.0 V to 3.6 V	-	4.4	-	-	-	-	-	pF

<sup>[1]</sup> All typical values are measured at nominal  $V_{\text{CC}}$ .

 $P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \Sigma (C_L \times V_{CC}^2 \times f_o)$  where:

f<sub>i</sub> = input frequency in MHz;

f<sub>o</sub> = output frequency in MHz;

C<sub>L</sub> = output load capacitance in pF;

V<sub>CC</sub> = supply voltage in V;

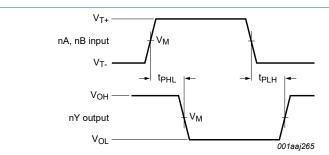
N = number of inputs switching;

 $\Sigma(C_L \times V_{CC}^2 \times f_o)$  = sum of the outputs.

 <sup>[2]</sup> t<sub>pd</sub> is the same as t<sub>PLH</sub> and t<sub>PHL</sub>.
 [3] C<sub>PD</sub> is used to determine the dynamic power dissipation (P<sub>D</sub> in μW).

#### Low-power dual 2-input NAND Schmitt trigger

### 12.1. Waveforms and test circuit



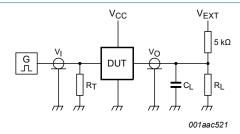
Measurement points are given in <u>Table 9</u>.

Logic levels:  $V_{OL}$  and  $V_{OH}$  are typical output voltage levels that occur with the output load.

### Fig. 7. The data input (nA or nB) to output (nY) propagation delays

**Table 9. Measurement points** 

Supply voltage	Input	Output		
V <sub>CC</sub>	V <sub>M</sub>	V <sub>I</sub>	$t_r = t_f$	V <sub>M</sub>
0.8 V to 3.6 V	0.5 × V <sub>CC</sub>	V <sub>CC</sub>	≤ 3.0 ns	0.5 × V <sub>CC</sub>



Test data is given in Table 10.

Definitions for test circuit:

R<sub>L</sub> = Load resistance;

C<sub>L</sub> = Load capacitance including jig and probe capacitance;

 $R_T$  = Termination resistance should be equal to the output impedance  $Z_0$  of the pulse generator;

 $V_{\text{EXT}}$  = External voltage for measuring switching times.

Fig. 8. Test circuit for measuring switching times

#### Table 10. Test data

Supply voltage	Load	V <sub>EXT</sub>			
V <sub>CC</sub>	CL	R <sub>L</sub> [1]	t <sub>PLH</sub> , t <sub>PHL</sub>	t <sub>PZH</sub> , t <sub>PHZ</sub>	t <sub>PZL</sub> , t <sub>PLZ</sub>
0.8 V to 3.6 V	5 pF, 10 pF, 15 pF and 30 pF	5 kΩ or 1 MΩ	open	GND	2 × V <sub>CC</sub>

[1] For measuring enable and disable times  $R_L = 5 \text{ k}\Omega$ .

For measuring propagation delays, setup and hold times and pulse width  $R_L$  = 1  $M\Omega$ .

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### Low-power dual 2-input NAND Schmitt trigger

## 13. Transfer characteristics

#### **Table 11. Transfer characteristics**

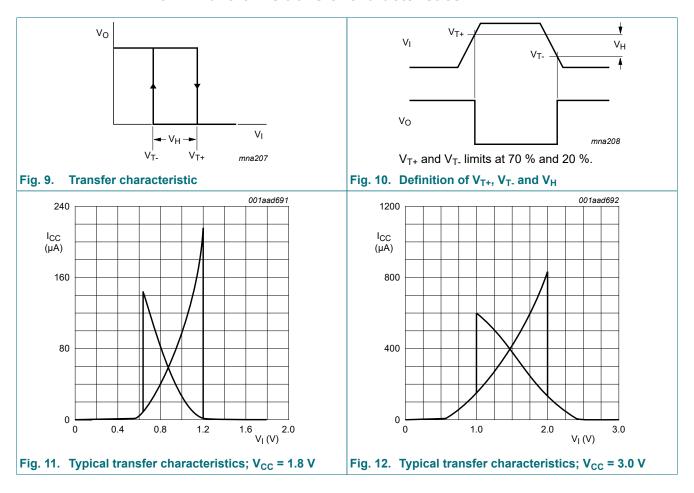
Voltages are referenced to GND (ground = 0 V); for test circuit see Fig. 8.

Symbol	Parameter	Conditions	T <sub>amb</sub> = 25 °C		T <sub>amb</sub> = -40 °C to +85 °C		T <sub>amb</sub> = -40 °C to +125 °C		Unit	
			Min	Тур	Max	Min	Max	Min	Max	-
V <sub>T+</sub>	positive-going threshold voltage	see Fig. 9 and Fig. 10								
		V <sub>CC</sub> = 0.8 V	0.30	-	0.60	0.30	0.60	0.30	0.62	V
		V <sub>CC</sub> = 1.1 V	0.53	-	0.90	0.53	0.90	0.53	0.92	V
		V <sub>CC</sub> = 1.4 V	0.74	-	1.11	0.74	1.11	0.74	1.13	V
		V <sub>CC</sub> = 1.65 V	0.91	-	1.29	0.91	1.29	0.91	1.31	V
		V <sub>CC</sub> = 2.3 V	1.37	-	1.77	1.37	1.77	1.37	1.80	V
		V <sub>CC</sub> = 3.0 V	1.88	-	2.29	1.88	2.29	1.88	2.32	V
V <sub>T-</sub>	negative-going	see Fig. 9 and Fig. 10								
	threshold voltage	V <sub>CC</sub> = 0.8 V	0.10	-	0.60	0.10	0.60	0.10	0.60	V
	Voltage	V <sub>CC</sub> = 1.1 V	0.26	-	0.65	0.26	0.65	0.26	0.65	V
		V <sub>CC</sub> = 1.4 V	0.39	-	0.75	0.39	0.75	0.39	0.75	V
		V <sub>CC</sub> = 1.65 V	0.47	-	0.84	0.47	0.84	0.47	0.84	V
		V <sub>CC</sub> = 2.3 V	0.69	-	1.04	0.69	1.04	0.69	1.04	V
		V <sub>CC</sub> = 3.0 V	0.88	-	1.24	0.88	1.24	0.88	1.24	V
V <sub>H</sub>	hysteresis voltage	(V <sub>T+</sub> - V <sub>T-</sub> ); see <u>Fig. 9</u> , <u>Fig. 10</u> , <u>Fig. 11</u> and <u>Fig. 12</u>								
		V <sub>CC</sub> = 0.8 V	0.07	-	0.50	0.07	0.50	0.07	0.50	V
		V <sub>CC</sub> = 1.1 V	0.08	-	0.46	0.08	0.46	0.08	0.46	V
		V <sub>CC</sub> = 1.4 V	0.18	-	0.56	0.18	0.56	0.18	0.56	V
		V <sub>CC</sub> = 1.65 V	0.27	-	0.66	0.27	0.66	0.27	0.66	V
		V <sub>CC</sub> = 2.3 V	0.53	-	0.92	0.53	0.92	0.53	0.92	V
		V <sub>CC</sub> = 3.0 V	0.79	-	1.31	0.79	1.31	0.79	1.31	V

**Product data sheet** 

### Low-power dual 2-input NAND Schmitt trigger

### 13.1. Waveforms transfer characteristics



#### Low-power dual 2-input NAND Schmitt trigger

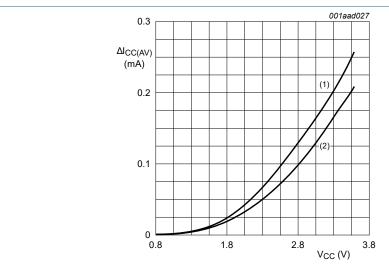
## 14. Application information

The slow input rise and fall times cause additional power dissipation which can be calculated using the following formula:

 $P_{add} = f_i \times (t_r \times \Delta I_{CC(AV)} + t_f \times \Delta I_{CC(AV)}) \times V_{CC}$  where:

- P<sub>add</sub> = additional power dissipation (μW);
- f<sub>i</sub> = input frequency (MHz);
- t<sub>r</sub> = input rise time (ns); 10 % to 90 %;
- t<sub>f</sub> = input fall time (ns); 90 % to 10 %;
- ΔI<sub>CC(AV)</sub> = average additional supply current (µA).

Average  $\Delta I_{CC(AV)}$  differs with positive or negative input transitions, as shown in Fig. 13.



- (1) Positive-going edge
- (2) Negative-going edge

Linear change of  $V_{\rm I}$  between 0.8 V and 2.0 V. All values given are typical, unless otherwise specified.

Fig. 13. Average I<sub>CC</sub> as a function of V<sub>CC</sub>

#### Low-power dual 2-input NAND Schmitt trigger

# 15. Package outline

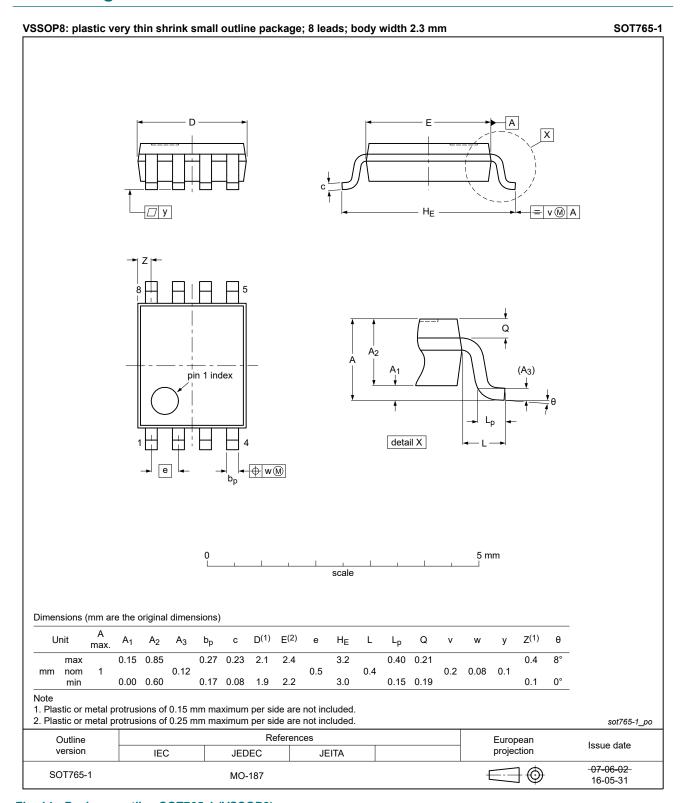


Fig. 14. Package outline SOT765-1 (VSSOP8)

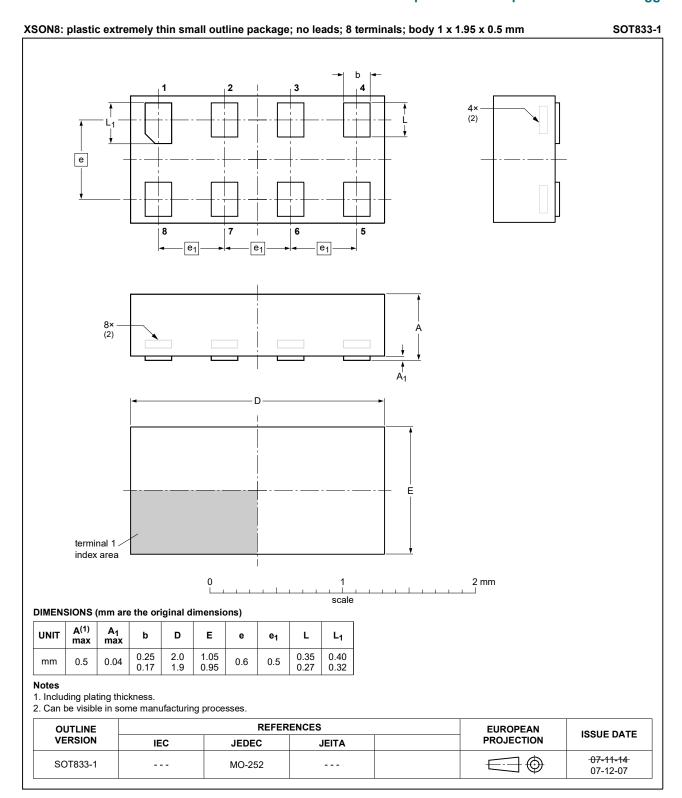


Fig. 15. Package outline SOT833-1 (XSON8)

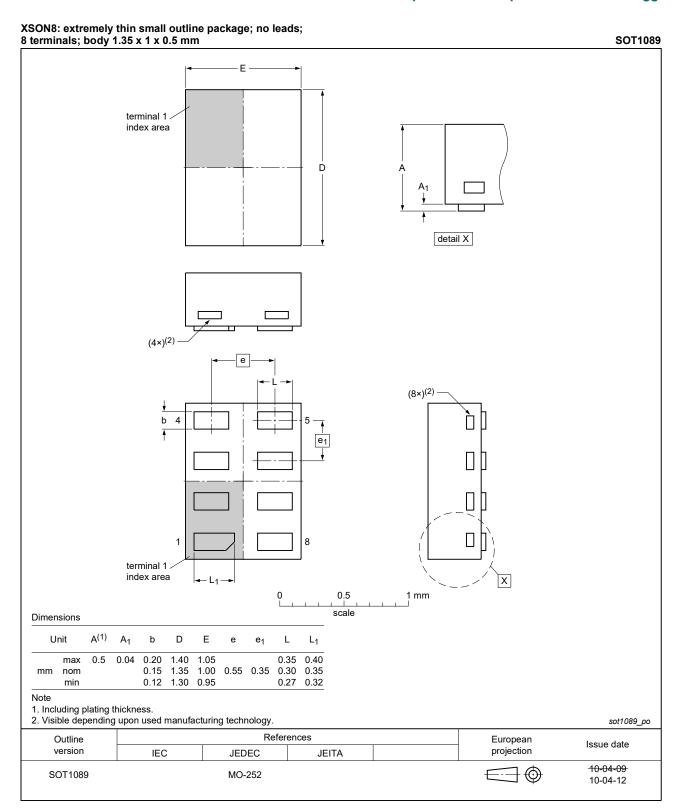


Fig. 16. Package outline SOT1089 (XSON8)

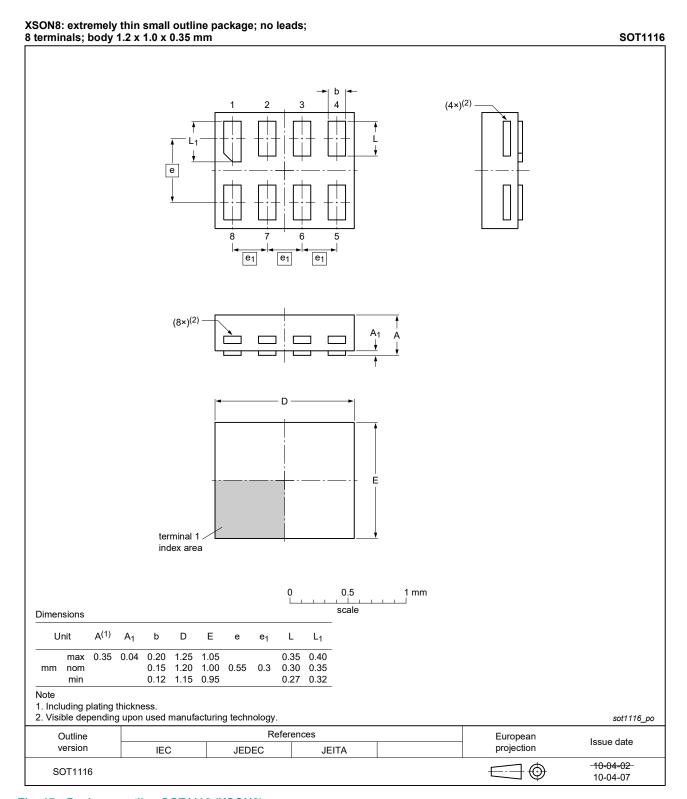


Fig. 17. Package outline SOT1116 (XSON8)

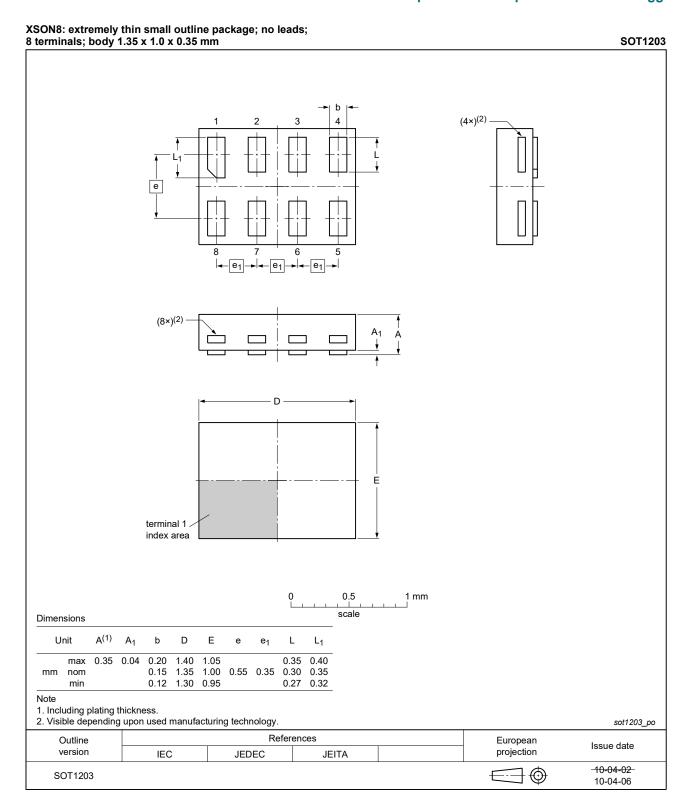


Fig. 18. Package outline SOT1203 (XSON8)

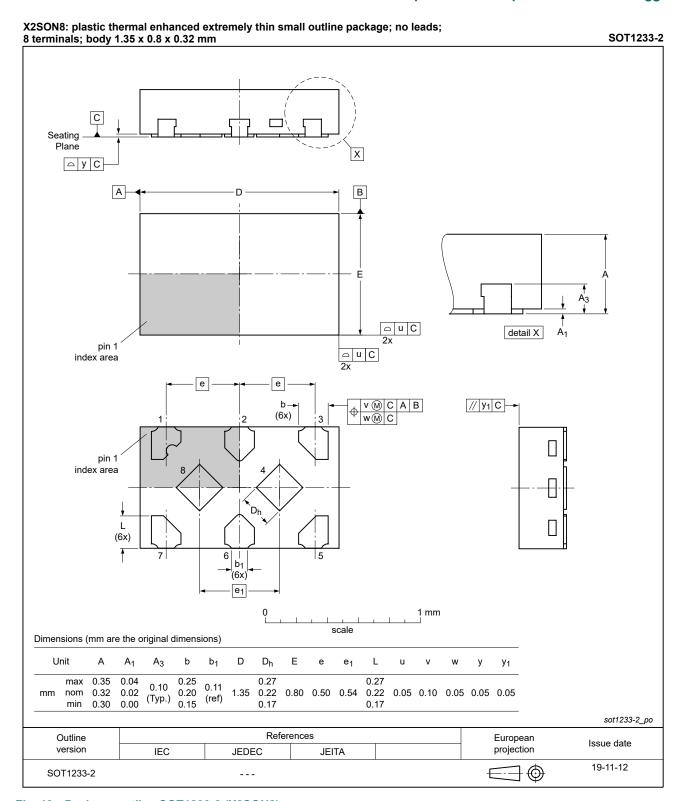


Fig. 19. Package outline SOT1233-2 (X2SON8)

### Low-power dual 2-input NAND Schmitt trigger

### 16. Abbreviations

#### **Table 12. Abbreviations**

Acronym	Description
CDM	Charged Device Model
DUT	Device Under Test
ESD	ElectroStatic Discharge
НВМ	Human Body Model

# 17. Revision history

### **Table 13. Revision history**

Document ID	Release date	Data sheet status	Change notice	Supersedes
74AUP2G132 v.11	20230726	Product data sheet	-	74AUP2G132 v.10
Modifications:	Section 2: I	ESD specification updated	d according to the la	atest JEDEC standard.
74AUP2G132 v.10	20230123	Product data sheet	-	74AUP2G132 v.9
Modifications:	Type numb	er 74AUP2G132GM (SO	T902-2/XQFN8) rer	noved.
74AUP2G132 v.9	20220622	Product data sheet	-	74AUP2G132 v.8
Modifications:	• <u>Section 1</u> a	X2SON8) package chang nd <u>Section 2</u> updated. P <sub>tot</sub> total power dissipatior	,	X2SON8) package. 2SON8) has been updated.
74AUP2G132 v.8	20170703	Product data sheet	-	74AUP2G132 v.7
Modifications:	<ul> <li>The format</li> </ul>	of this data sheet has be	en redesigned to co	mnly with the identity
	<ul><li>Legal texts</li><li>Type numb</li></ul>	of Nexperia. have been adapted to the er 74AUP2G132GX (SOT er 74AUP2G132GD remo	e new company nar Γ1233 / X2SON8) a	ne where appropriate.
74AUP2G132 v.7	<ul><li>Legal texts</li><li>Type numb</li></ul>	of Nexperia. have been adapted to the er 74AUP2G132GX (SOT	e new company nar Γ1233 / X2SON8) a	ne where appropriate.
74AUP2G132 v.7 Modifications:	<ul><li>Legal texts</li><li>Type numb</li><li>Type numb</li><li>20130208</li></ul>	of Nexperia. have been adapted to the er 74AUP2G132GX (SOT er 74AUP2G132GD remo	e new company nar Γ1233 / X2SON8) a oved.	ne where appropriate. dded. 74AUP2G132 v.6
	<ul><li>Legal texts</li><li>Type numb</li><li>Type numb</li><li>20130208</li></ul>	of Nexperia. have been adapted to the er 74AUP2G132GX (SOT er 74AUP2G132GD remo	e new company nar Γ1233 / X2SON8) a oved.	ne where appropriate. dded. 74AUP2G132 v.6
Modifications:	<ul><li>Legal texts</li><li>Type numb</li><li>Type numb</li><li>20130208</li><li>For type nu</li></ul>	of Nexperia. have been adapted to the er 74AUP2G132GX (SOTer 74AUP2G132GD removed Product data sheet mber 74AUP2G132GD X	e new company nar Γ1233 / X2SON8) a oved.	ne where appropriate. dded.  74AUP2G132 v.6 ed to XSON8.
Modifications: 74AUP2G132 v.6	Legal texts     Type numb     Type numb     20130208     For type nu 20120803	of Nexperia. have been adapted to the er 74AUP2G132GX (SOTer 74AUP2G132GD removed Product data sheet mber 74AUP2G132GD X	e new company nar Γ1233 / X2SON8) a oved.	ne where appropriate. dded.  74AUP2G132 v.6 ed to XSON8.  74AUP2G132 v.5
Modifications: 74AUP2G132 v.6 74AUP2G132 v.5	<ul> <li>Legal texts</li> <li>Type numb</li> <li>Type numb</li> <li>20130208</li> <li>For type nu</li> <li>20120803</li> <li>20111201</li> </ul>	of Nexperia. have been adapted to the er 74AUP2G132GX (SOTer 74AUP2G132GD removed Product data sheet	e new company nar Γ1233 / X2SON8) a oved.	ne where appropriate. dded.  74AUP2G132 v.6 ed to XSON8.  74AUP2G132 v.5  74AUP2G132 v.4
Modifications: 74AUP2G132 v.6 74AUP2G132 v.5 74AUP2G132 v.4	<ul> <li>Legal texts</li> <li>Type numb</li> <li>Type numb</li> <li>20130208</li> <li>For type numb</li> <li>20120803</li> <li>20111201</li> <li>20101104</li> </ul>	of Nexperia. have been adapted to the er 74AUP2G132GX (SOTer 74AUP2G132GD removed by the experiment of	e new company nar Γ1233 / X2SON8) a oved.	ne where appropriate. dded.  74AUP2G132 v.6 ed to XSON8.  74AUP2G132 v.5 74AUP2G132 v.4 74AUP2G132 v.3

### 18. Legal information

#### Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
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Product [short] data sheet	Production	This document contains the product specification.

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